

Part Number	$V_{(BR)DSS}$ Drain-to-Source Breakdown Voltage (V)	$R_{DS(on)}$ On-State Resistance (Ω)	I_D Continuous Drain Current 25°C (A)	I_D Pulse Drain Current 100°C (A)	R_{θ} Max. Thermal Resistance (°C/W)	P_D Max. Power Dissipation (W)	Fax on Demand Number	Case Outline Key
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Module

HEX-Pak Module

N-Channel

Parallel Chip

IRFK4H150	100	0.014	145	580	.25	500	27104	H19
IRFK4J150	100	0.014	145	580	.25	500	27104	
IRFK6H150	100	0.01	150	720	.2	625	27110	
IRFK6J150	100	0.01	150	720	.2	625	27110	
IRFK4H250	200	0.021	108	432	.25	500	27105	
IRFK4J250	200	0.021	108	432	.25	500	27105	
IRFK6H250	200	0.015	140	560	.2	625	27111	
IRFK6J250	200	0.015	140	560	.2	625	27111	
IRFK4H350	400	0.075	50	200	.25	500	27106	
IRFK4J350	400	0.075	50	200	.25	500	27106	
IRFK6H350	400	0.05	75	300	.2	625	27112	
IRFK6J350	400	0.05	75	300	.2	625	27112	
IRFK4H450	500	0.1	44	176	.25	500	27107	
IRFK4J450	500	0.1	44	176	.25	500	27107	
IRFK6H450	500	0.067	66	264	.2	625	27113	



TO-240AA

